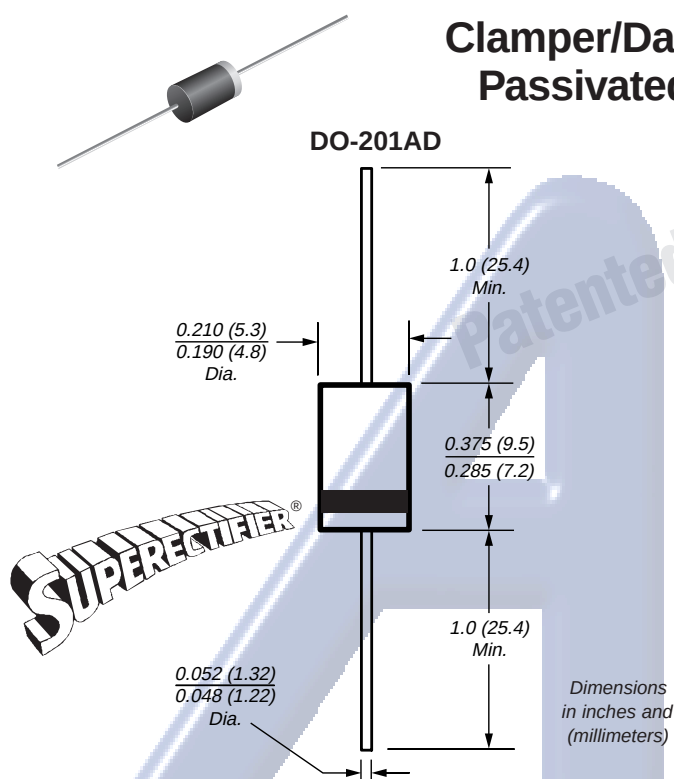




New Product

CGP30 and DGP30

Vishay Semiconductors
formerly General SemiconductorClamper/Damper Glass
Passivated RectifierReverse Voltage 1400 to 1500V
Forward Current 3.0A

*Glass-plastic encapsulation technique is covered by Patent No. 3,996,602 and brazed-lead assembly by Patent No. 3,930,306

Features

- Specially designed for clamping circuits, horizontal deflection systems and damper applications
- Plastic package has Underwriters Laboratories Flammability Classification 94V-0
- High temperature metallurgically bonded construction
- Cavity-free glass passivated junction
- 3.0 ampere operation at $T_A=50^\circ\text{C}$ with no thermal runaway
- Typical I_R less than $0.1\mu\text{A}$
- Capable of meeting environmental standards of MIL-S-19500
- High temperature soldering guaranteed: $350^\circ\text{C}/10$ seconds, 0.375" (9.5mm) lead length, 5 lbs. (2.3kg) tension

Mechanical Data

Case: JEDEC DO-201AD, molded plastic over glass body**Terminals:** Plated axial leads, solderable per MIL-STD-750, Method 2026**Polarity:** Color band denotes cathode end**Mounting Position:** Any**Weight:** 0.04 oz., 1.12 g**Packaging codes/options:**

1/Bulk - 1.5K per container, 15K per box

4/1.4K per 13" reel, 5.6K per box

23/1K per ammo mag., 9K per box

Maximum Ratings & Thermal Characteristics Ratings at 25°C ambient temperature unless otherwise specified.

Parameter	Symbol	CGP30	DGP30	Unit
Maximum repetitive peak reverse voltage	V_{RRM}	1400	1500	V
Maximum RMS voltage	V_{RMS}	980	1050	V
Maximum DC blocking voltage	V_{DC}	1400	1500	V
Maximum average forward rectified current 0.375" (9.5mm) lead length at $T_A = 50^\circ\text{C}$	$I_{F(AV)}$	3.0		A
Peak forward surge current 8.3ms single half sine wave superimposed on rated load (JEDEC Method) at $T_A = 50^\circ\text{C}$	I_{FSM}	100		A
Maximum full load reverse current full cycle average 0.375" (9.5mm) lead length at $T_A = 70^\circ\text{C}$	$I_{R(AV)}$	200		μA
Typical thermal resistance (Note 1)	$R_{\theta JA}$	20		$^\circ\text{C}/\text{W}$
Operating junction and storage temperature range	T_J, T_{STG}	-65 to +175		$^\circ\text{C}$

Electrical Characteristics Ratings at 25°C ambient temperature unless otherwise specified.

Parameter	Symbol	CGP30	DGP30	Unit
Maximum instantaneous forward voltage at 3.0A	V_F	1.2		V
Maximum DC reverse current $T_A = 25^\circ\text{C}$ at rated DC blocking voltage $T_A = 100^\circ\text{C}$	I_R	5.0 100		μA
Maximum reverse recovery time at $I_F = 0.5\text{A}$, $I_R = 50\text{mA}$	t_{rr}	15	20	μs
Maximum reverse recovery time at $I_F=0.5\text{A}$, $I_R=1.0\text{A}$, $I_{rr}=0.25\text{A}$ typical maximum	t_{rr}	1.0 2.0		μs
Typical junction capacitance at 4.0V, 1MHz	C_J	40		pF

Note: (1) Thermal resistance from junction to ambient at 0.375" (9.5mm) lead length, with leads attached to heat sink

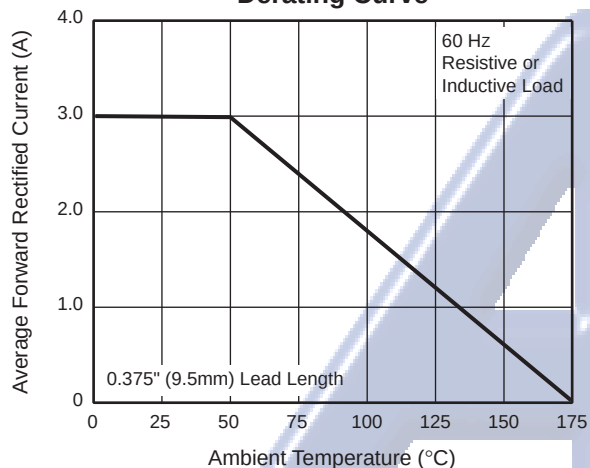
CGP30 and DGP30

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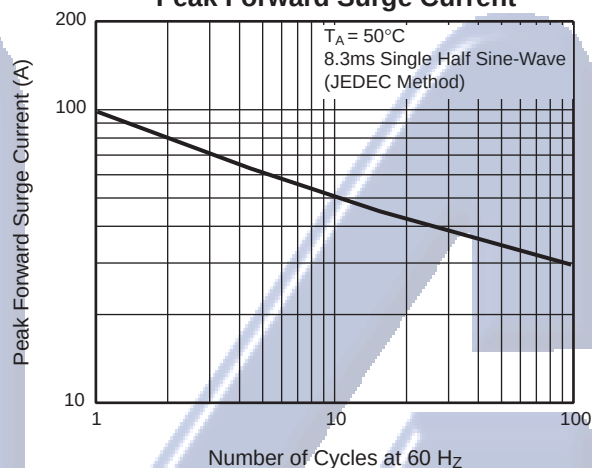


Ratings and Characteristic Curves ($T_A = 25^\circ\text{C}$ unless otherwise noted)

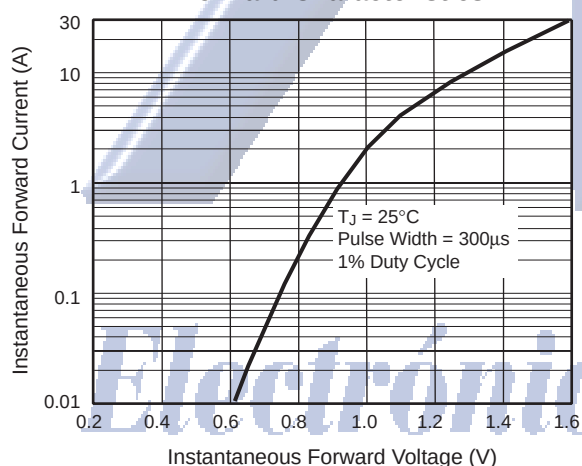
**Fig. 1 – Forward Current
Derating Curve**



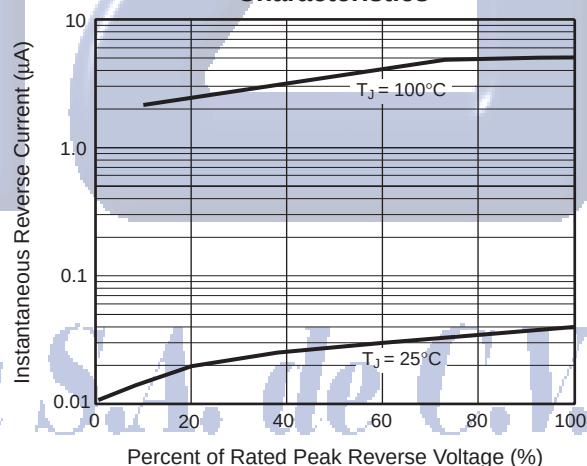
**Fig. 2 – Maximum Non-Repetitive
Peak Forward Surge Current**



**Fig. 3 – Typical Instantaneous
Forward Characteristics**



**Fig. 4 – Typical Reverse
Characteristics**



**Fig. 5 – Typical Junction
Capacitance**

